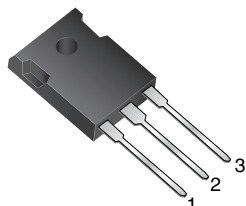
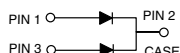


## Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



TO-3P (TO-247AD)



RoHS  
COMPLIANT

### FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max.10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

### MECHANICAL DATA

**Case:** TO-3P (TO-247AD)

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

|                       |                        |
|-----------------------|------------------------|
| $I_{F(AV)}$           | 30 A                   |
| $V_{RRM}$             | 35 V, 45 V, 50 V, 60 V |
| $I_{FSM}$             | 200 A                  |
| $V_F$                 | 0.58 V, 0.63 V         |
| $I_R$                 | 150 $\mu$ A            |
| $T_J$ max.            | 175 °C                 |
| Package               | TO-3P (TO-247AD)       |
| Circuit configuration | Common cathode         |

### MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise noted)

| PARAMETER  | SYMBOL                          | MBR30H35PT  | MBR30H45PT | MBR30H50PT | MBR30H60PT | UNIT |
|--|---------------------------------|-------------|------------|------------|------------|------|
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>                | 35          | 45         | 50         | 60         | V    |
| Maximum working peak reverse voltage   | V <sub>RWM</sub>                | 35          | 45         | 50         | 60         | V    |
| Maximum DC blocking voltage  | V <sub>DC</sub>                 | 35          | 45         | 50         | 60         | V    |
| Maximum average forward rectified current (fig. 1)   | I <sub>F(AV)</sub>              | 30          |            |            |            | A    |
| Non-repetitive avalanche energy per diode at 25 °C, I <sub>AS</sub> = 1.5 A, L = 10 mH       | E <sub>AS</sub>                 | 80          |            |            |            | mJ   |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I <sub>FSM</sub>                | 200         |            |            |            | A    |
| Peak repetitive reverse surge current per diode  | I <sub>RRM</sub> <sup>(1)</sup> | 2.0         |            | 1.0        |            | A    |
| Peak non-repetitive reverse energy (8/20 μs waveform)  | E <sub>RSM</sub>                | 30          |            | 20         |            | mJ   |
| Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 Ω            | V <sub>C</sub>                  | 25          |            |            |            | kV   |
| Voltage rate of change (rated V <sub>R</sub> )   | dV/dt                           | 10 000      |            |            |            | V/μs |
| Operating junction temperature range   | T <sub>J</sub>                  | -65 to +175 |            |            |            | °C   |
| Storage temperature range  | T <sub>STG</sub>                | -65 to +175 |            |            |            | °C   |

#### Note

<sup>(1)</sup> 2.0  $\mu$ s pulse width,  $f = 1.0$  kHz



| ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |             |                                     |                                     |                          |      |                          |      |               |
|---|-------------|-------------------------------------|-------------------------------------|--------------------------|------|--------------------------|------|---------------|
| PARAMETER   | SYMBOL      | TEST CONDITIONS                     |                                     | MBR30H35PT<br>MBR30H45PT |      | MBR30H50PT<br>MBR30H60PT |      | UNIT          |
|   |             |                                     |                                     | TYP.                     | MAX. | TYP.                     | MAX. |               |
| Maximum instantaneous forward voltage per diode   | $V_F^{(1)}$ | $I_F = 20\text{ A}$                 | $T_J = 25\text{ }^{\circ}\text{C}$  | -                        | 0.66 | -                        | 0.74 | V             |
|   |             | $I_F = 20\text{ A}$                 | $T_J = 125\text{ }^{\circ}\text{C}$ | 0.54                     | 0.58 | 0.60                     | 0.63 |               |
|   |             | $I_F = 30\text{ A}$                 | $T_J = 25\text{ }^{\circ}\text{C}$  | -                        | 0.73 | -                        | 0.83 |               |
|   |             | $I_F = 30\text{ A}$                 | $T_J = 125\text{ }^{\circ}\text{C}$ | 0.62                     | 0.66 | 0.66                     | 0.70 |               |
| Maximum reverse current at rated $V_R$ per diode  | $I_R^{(2)}$ | $T_J = 25\text{ }^{\circ}\text{C}$  |                                     | -                        | 150  | -                        | 150  | $\mu\text{A}$ |
|   |             | $T_J = 125\text{ }^{\circ}\text{C}$ |                                     | 6.0                      | 25   | 4.0                      | 25   | mA            |

## Notes

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 40\text{ ms}$

| THERMAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                 |            |            |            |            |                      |
|--|-----------------|------------|------------|------------|------------|----------------------|
| PARAMETER  | SYMBOL          | MBR30H35PT | MBR30H45PT | MBR30H50PT | MBR30H60PT | UNIT                 |
| Thermal resistance, junction to case per diode                                       | $R_{\theta JC}$ | 1.4        |            |            |            | $^{\circ}\text{C/W}$ |

| ORDERING INFORMATION (Example) |                  |                 |              |               |               |
|--------------------------------|------------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N    | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-247AD                       | MBR30H45PT-E3/45 | 6.13            | 45           | 30/tube       | Tube          |



## RATINGS AND CHARACTERISTICS CURVES ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

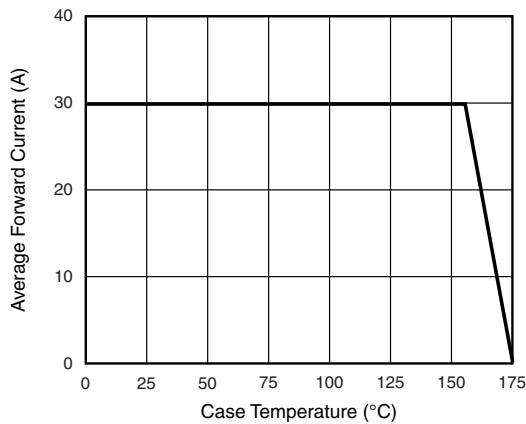


Fig. 1 - Forward Current Derating Curve

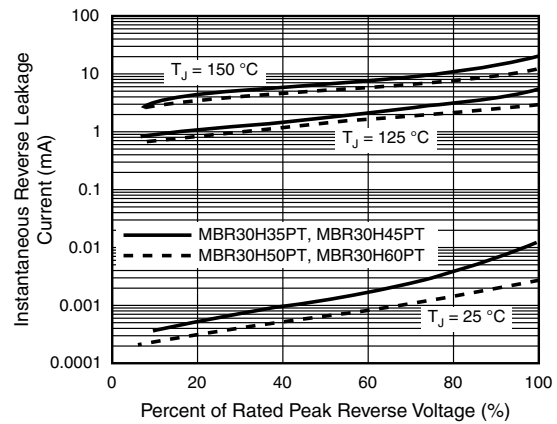


Fig. 4 - Typical Reverse Characteristics Per Diode

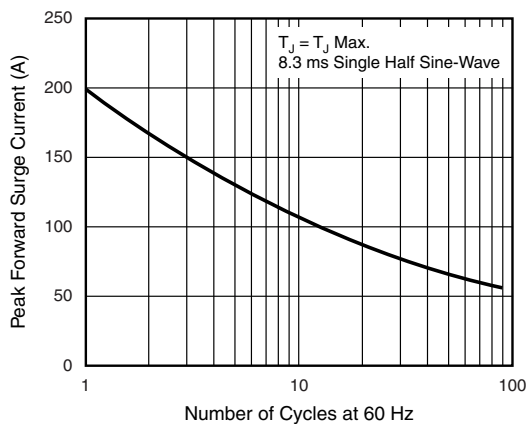


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

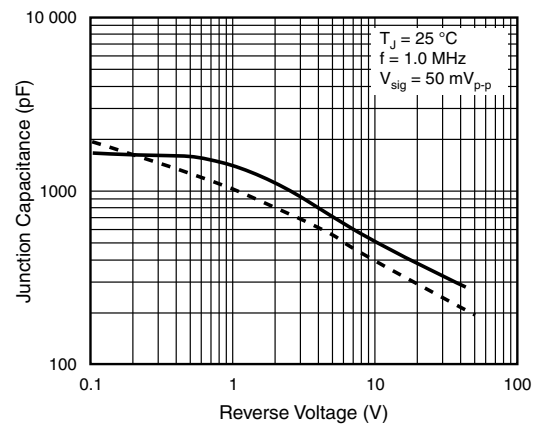


Fig. 5 - Typical Junction Capacitance Per Diode

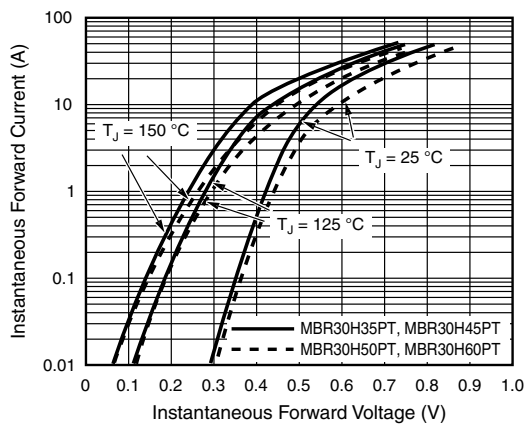


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

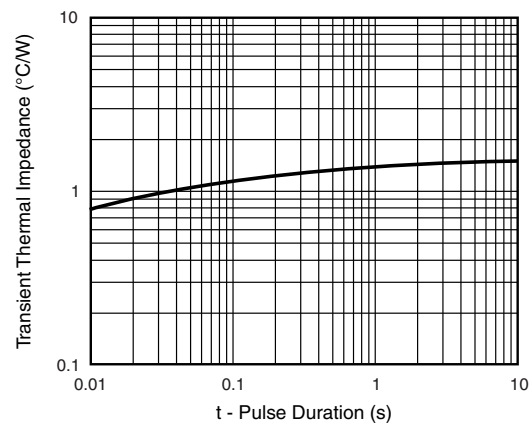
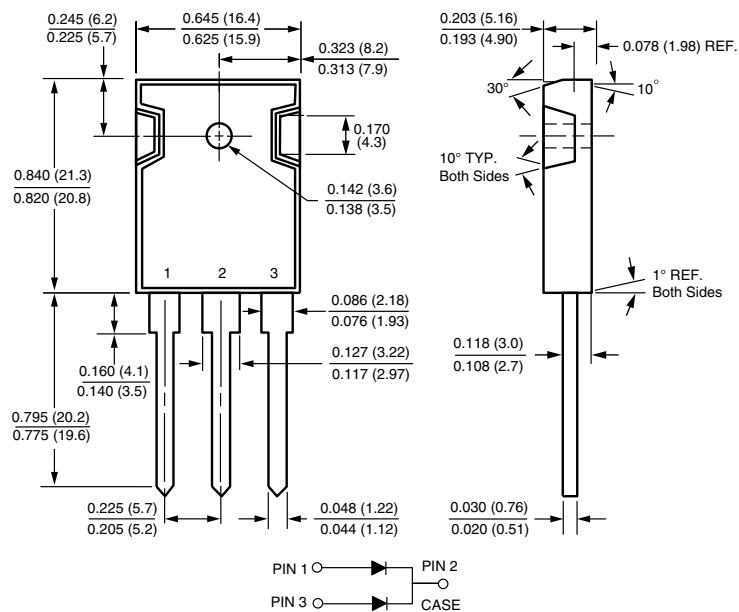


Fig. 6 - Typical Transient Thermal Impedance Per Diode



## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-3P (TO-247AD)





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